
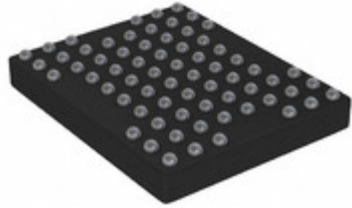



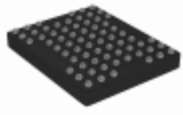

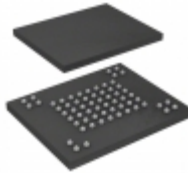



|  |   |
|--|---|
|   | <b>TC58BVG0S3HBAI6</b>  |
|  | <b>Hersteller-Teilenummer:</b> <a href="#">TC58BVG0S3HBAI6</a>          |
|   | <b>Hersteller / Marke:</b> <a href="#">Toshiba Memory America, Inc.</a> |
|  | <b>Teil der Beschreibung:</b> IC FLASH 1G PARALLEL 67VFBGA              |
| <b>Datenblätter:</b>  <a href="#">TC58BVG0S3HBAI6.pdf</a> |   |
| <b>RoHs Status:</b> Bleifrei / RoHS-konform  |   |
| <b>Lagerzustand:</b> New original, 9875 pcs Stock Available.   |   |
| <b>Liefern von:</b> Hong Kong  |   |
| <b>Versandweg:</b> DHL/Fedex/TNT/UPS/EMS   |   |
| Image may be representation.<br>See specs for product details.   |   |

### Spezifikationen

|   |   |
|---|---|
| Teilenummer                               | TC58BVG0S3HBAI6   |
| Hersteller                                | Toshiba Memory America, Inc.                                  |
| Beschreibung                              | IC FLASH 1G PARALLEL 67VFBGA                                  |
| Kategorie                                 | <a href="#">Integrierte Schaltungen (ICs) &gt; Erinnerung</a> |
| Teilstatus                                | 9875 pcs Stock  |
| detaillierte Beschreibung                 | FLASH - NAND (SLC) Memory IC 1Gb (128M x 8)                   |
| Serie                                     | Benand™   |
| Technologie                               | FLASH - NAND (SLC)  |
| Betriebstemperatur                        | -40°C ~ 85°C (TA)   |
| Befestigungsart                           | Surface Mount   |
| Verpackung / Gehäuse                      | 67-VFBGA  |
| Supplier Device-Gehäuse                   | 67-VFBGA (6.5x8)  |
| Spannungsversorgung                       | 2.7 V ~ 3.6 V   |
| Speichertyp                               | Non-Volatile  |
| Speichergröße                             | 1Gb (128M x 8)  |
| Zugriffszeit                              | 25ns  |
| Speicherformat                            | FLASH   |
| Schreibzyklus Zeit - Wort, Seite          | 25ns  |
| Speicherschnittstelle                     | Parallel  |
| Verpackung                                | Tray  |
| Bleifreier Status / RoHS-Status           | Lead free / RoHS Compliant                                    |
| Feuchtigkeitsempfindlichkeitsniveau (MSL) | 3 (168 Hours)   |
| Andere Namen                              | TC58BVG0S3HBAI6JDH  |

TC58BVG0S3HBAI6 ist neu im Original, Suche TC58BVG0S3HBAI6 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie TC58BVG0S3HBAI6 Toshiba Memory America, Inc. mit Garantie und Vertrauen. Anfrage TC58BVG0S3HBAI6: [Info@Y-IC.com](mailto:Info@Y-IC.com)

Sie können auch interessiert sein:

|  |   |  |   |
|--|---|--|---|
|  <p><b>TC58BVG0S3HBAI6</b><br/>Toshiba Semiconductor and Storage<br/>IC EEPROM 1GBIT 25NS<br/>67VFBGA</p> |  <p><b>TC58A040F-ELAGP</b><br/>TOS<br/>TOS SOP-28</p>            |  <p><b>TC58BVG0S3HBAI4</b><br/>Toshiba Memory America, Inc.<br/>IC FLASH 1G PARALLEL<br/>63TFBGA</p>     |  <p><b>TC58BVG0S3HBAI4</b><br/>Toshiba Semiconductor and Storage<br/>IC EEPROM 1GBIT 25NS<br/>63FBGA</p> |
|  <p><b>TC58BVG0S3HTA00</b><br/>Toshiba Memory America, Inc.<br/>IC FLASH 1G PARALLEL<br/>48TSOP I</p>     |  <p><b>TC58BVG0S3HTAI0B4Q</b><br/>TOSHIBA<br/>TOSHIBA TSOP48</p> |  <p><b>TC58BVG0S3HTAI0</b><br/>Toshiba Semiconductor and Storage<br/>IC EEPROM 1GBIT 25NS<br/>48TSOP</p> |  <p><b>TC58BVG0S3HTA00</b><br/>Toshiba Semiconductor and Storage<br/>IC EEPROM 1GBIT 25NS<br/>48TSOP</p> |

### heiße Teile

Mehr

|                    |                  |                     |                    |                  |
|--------------------|------------------|---------------------|--------------------|------------------|
| TC55V1664BJ-12     | TC55V2001FI-85L  | TC55V2161FTI-85A    | TC55V328AJ-15      | TC55V328BJ-15    |
| TC55V4001AFT-70L   | TC55V400FT-85    | TC55V8128BFT-12     | TC55V8128BJ-12     | TC55V8512FT-15   |
| TC55VBM316ASGN55   | TC55VCM216ASGN55 | TC55VCM216ASTN55    | TC55VCM216ASTN55LA | TC55VZM208AFTN12 |
| TC55VZM216AFTN12LA | TC571001D        | TC572502ECTTR       | TC57256AD-12       | TC57256AD-15     |
| TC57512AD-15       | TC58128FT        | TC5816BFT           | TC584000F          | TC58A040F        |
| TC58BVG0S3HBAI6    | TC58BVG0S3HTA00  | TC58BVG0S3HTA00     | TC58BVG1S3HTA00    | TC58BVG1S3HTA00  |
| TC58BYG0S3HBAI4    | TC58BYG0S3HBAI4  | TC58BYG0S3HBAI4JDH  | TC58C128AFTI       | TC58C256AXB      |
| TC58DVG02A5TA00    | TC58DVG14B1TG00  | TC58DVG3S0ETA00/B4J | TC58DVM72A1FT00    | TC58DVM72A1TG00  |
| TC58DVM72A1XBJ1    | TC58DVM82F1TGIO  | TC58DVM82F1TGIO     | TC58DVM92A1FT      | TC58DVM92A2FT00  |
| TC58DVM92A5TA00    | TC58DVM92A5TAJO  | TC58DVM92F1TGIO     | TC58DYG02D5BAI4    | TC58EVG0S8EBAIB  |

Contact us: [Info@Y-IC.com](mailto:Info@Y-IC.com)

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

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